



Product Features

- High dynamic range downconverter with integrated LO, IF, & RF amps
- RF: 800 915 MHz
- IF: 65 120 MHz
- +37 dBm Output IP3
- +20 dBm Output P1dB
- 5 dB Noise Figure
- +5V Single supply operation
- Pb-free 6mm 28-pin QFN package
- Low-side LO configuration
- Common footprint with other PCS/UMTS versions

Specifications (1)

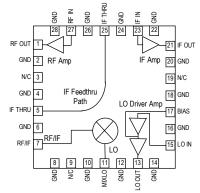
Product Description

The CV110-1A is a high linearity downconverter designed to meet the demanding issues for performance, functionality, and cost goals of current and next generation mobile infrastructure. It provides high dynamic range performance in a low profile surfacemount leadless package that measures 6×6 mm square.

Functionality includes RF amplification, frequency conversion and IF amplification, while an integrated LO driver amplifier powers the passive mixer. The MCM is implemented with reliable and mature GaAs MESFET and InGaP HBT technology.

Typical applications include frequency downconversion used in CDMA/GSM/TDMA, CDMA2000, W-CDMA, and EDGE 2.5G and 3G mobile base transceiver stations for cellular frequency bands.

Functional Diagram



Parameters	Units	Min	Тур	Max	Comments
RF Frequency Range	MHz		800 - 915		
LO Frequency Range	MHz		680 - 850		
IF Center Frequency Range	MHz		65 – 120		See note 2
% Bandwidth around IF center frequency	%		±7.5		See note 3
IF Test Frequency	MHz		75		
SSB Conversion Gain	dB		22		Temp = $25 \degree C$
Gain Drift over Temp (-40 to 85 °C)	dB		±1.5		Referenced to +25 °C
Output IP3	dBm		+37		See note 4
Output IP2	dBm		+45		See note 4
Output 1dB Compression Point	dBm		+20		
Noise Figure	dB		5		See note 5
LO Input Drive Level	dBm	-2.5	0	+2.5	
LO-RF Isolation	dB		60		See note 6
LO-IF Isolation	dB		40		$P_{LO} = 0 dBm$
Return Loss: RF Port	dB		15		
Return Loss: LO Port	dB		10		
Return Loss: IF Port	dB		15		
Operating Supply Voltage	V	+4.9	+5	+5.1	
Supply Current	mA	290	360	480	
FIT Rating	$failures/_{1E9 hrs}$			72.1	@ 70° C ambient, 90% confidence
Thermal Resistance	°C / W			27	
Junction Temperature	°C			160	See note 7

Specifications when using the application specific circuit (shown on page 3) with a low side LO = 0 dBm in a downconverting application over the operating case temperature range. IF matching components affect the center IF frequency. Proper component values for other IF center frequencies can be found in the IF Amplifier Matching Table or by e-mailing to sjcapps@tqs.com. The IF bandwidth of the converter is defined as 15% around any center frequency in so operating IF frequency range. The bandwidth is determined with external components. Specifications are valid around the total 47.5% bandwidth. ie, with a center frequency of 240 MHz, the specifications are valid from 80 ± 6 MHz. Assumes the supply voltage = +5 V. OIP3 is measured with $\Delta f = 1$ MHz with IF_{out} = 5 dBm / tone. Assumes LO injection noise is filtered at the thermal noise floor, -174 dBm/Hz, at the RF, IF, and Image frequencies. L-R Isolation is referenced to an LO injection of 0 dBm. The L-R performance shown also includes the isolation due to an external SAW filter between the RF amplifier and mixer. The maximum junction temperature ensures a minimum MTTF rating of 1 million hours of usage.

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Absolute Maximum Rating

Parameter	Rating
Storage Temperature	-55 to +125 °C
DC Voltage	+6 V
Max. Junction Temperature, Tj	+160 °C
RF Input (continuous)	+2 dBm

Ordering Information

Part No.	Description
CV110-1AF	Cellular-band High Linearity Downconverter (lead-free/RoHS-compliant 6x6mm QFN package)
CV110-1APCB75	Fully Assembled Eval. Board, IF = 75MHz

Operation of this device above any of these parameters may cause permanent damage.

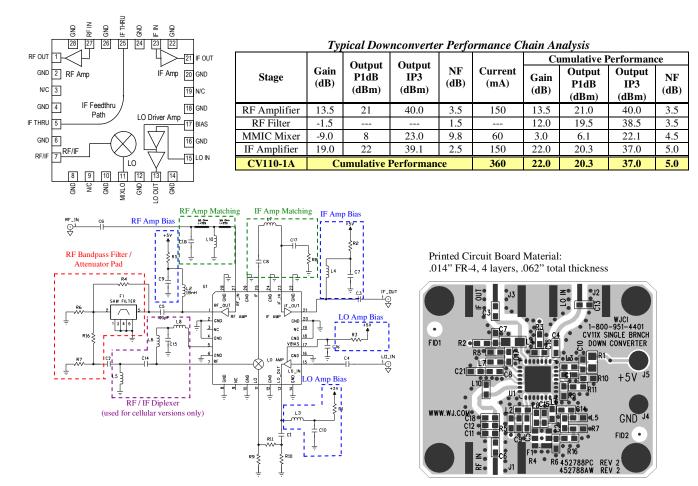
Standard T/R size = 500 pieces on a 7" reel

Specifications and information are subject to change without notice





Device Architecture / Application Circuit Information



CV110-1A: The application circuit can be broken up into four main functions as denoted in the colored dotted areas above: RF/IF diplexing (purple), amplifier matching (green), filtering (red), and dc biasing (blue). There are various placeholders for chip components in the circuit schematic so that a common PCB can be used for all WJ single-branch converters. Additional placeholders for other optional functions such as filtering are also included.

RF / **IF Amplifier Matching:** The RF amplifier requires a shunt matching element for optimal gain and input return loss performance. The IF amplifier requires matching elements to optimize the performance of the amplifier to the desired IF center frequency. Since IF bandwidths are typically on the order of 5 to 10%, a simple two element matching network, in the form of either a high-pass or low-pass filter structure, is sufficient to match the MMIC IF amplifier over these narrow bandwidths. Proper component values for other IF center frequencies can be found in the IF Amplifier Matching Table or by emailing to sjcapps@tqs.com.

RF Bandpass Filtering: Bandpass filtering is recommended to reject the image frequencies and achieve the best noise figure performance

with the downconverter. The bandpass filter, implemented with a SAW filter on the application circuit, allows for the suppression of noise from the image frequency. It is permissible to not use a filter and use a 2 dB pad with R6, R7, and R16 instead with slightly degraded noise figure performance. Standard WJ evaluation boards will have the 2 dB pad in place.

External Diplexer: In a downconversion application, the incoming RF signal impinges on the switching elements of the mixer; the interaction with these switches produces a signal at the IF frequency. The two signals (RF and IF) are directed to the appropriate ports by the external diplexer. A four-element diplexer is used in the circuit implementation (L8 and C2 are not used). Pin 5 contains the IF signal and allows the signal to be transferred to pin 25 for the convenience of PCB layouts.

DC biasing: DC bias must be provided for the RF, LO and IF amplifiers in the converter. R1 sets the operating current for the last stage of the LO amplifier and is chosen to optimize the mixer LO drive level. Proper RF chokes and bypass capacitors are chosen for proper amplifier biasing at the intended frequency of operation. The "+5 V" dc bias should be supplied directly from a voltage regulator.

IF Amplifier Matching

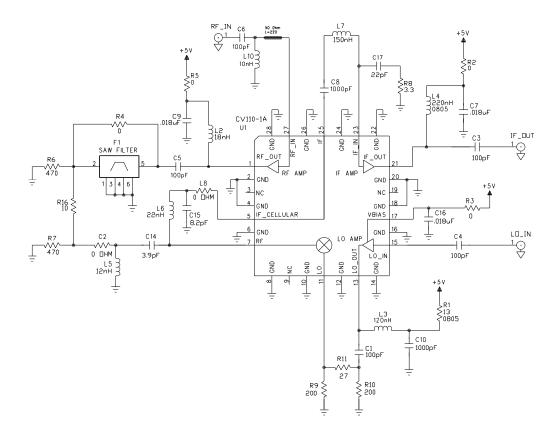
IF Ampliner Matching											
Frequency (MHz)	40	50	75	100	125	130	155	169	180	210	240
L7 (nH)	470	430	150	150	120	120	100	82	82	82	56
C17 (pF)	24	15	22	10	8.2	6.8	5.6	5.0	4.7	3.3	3.9
R8 (ohms)	4.7	4.7	3.3	2.2	2.2	2.2	2.2	2.2	2.2	2.2	2.2
L4 (nH)	470	240	330	330	330	330	330	330	330	220	220

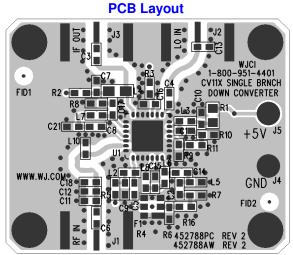
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Downconverting Application Circuit: CV110-1APCB75 RF = 800 – 915 MHz, IF = 75 MHz





Circuit Board Material: .014" FR-4, 4 layers, .062" total thickness

Ref. Desig.ComponentR113 Ω chip resistor, size 0805R2, R3, R4, R5, C2, L80 Ω chip resistorR6, R7470 Ω chip resistorR83.3 Ω chip resistorR9, R10200 Ω chip resistorR1127 Ω chip resistorR1610 Ω chip resistorC1, C3, C4, C5, C6100 pF chip capacitorC7, C9, C160.018 μ F chip capacitorC11, C12, C13,Shown in silkscreen, but notC18, C21, F1used in actual circuit.C1722 pF chip capacitorC1722 pF chip capacitorL218 nH chip inductorL3120 nH chip inductorL4220 nH chip inductorL512 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	Bill of Materials				
R2, R3, R4, R5, C2, L8 0 Ω chip resistor R6, R7 470 Ω chip resistor R8 3.3 Ω chip resistor R9, R10 200 Ω chip resistor R11 27 Ω chip resistor R16 10 Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 μ F chip capacitor C8, C10 1000 pF chip capacitor C11, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C15 8.2 pF chip capacitor C17 22 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	Ref. Desig.	Component			
R6, R7 470 Ω chip resistor R8 $3.3 Ω$ chip resistor R9, R10 200 Ω chip resistor R11 27 Ω chip resistor R16 10 Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 μF chip capacitor C8, C10 1000 pF chip capacitor C11, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C17 22 pF chip capacitor C17 22 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	R1	13 Ω chip resistor, size 0805			
R8 3.3Ω chip resistor R9, R10 200Ω chip resistor R11 27Ω chip resistor R16 10Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 $0.018 \ \mu\text{F}$ chip capacitor C8, C10 1000 pF chip capacitor C1, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C15 $8.2 \ pF$ chip capacitor C17 $22 \ pF$ chip capacitor C13 $120 \ nH \ chip inductor$ L2 $18 \ nH \ chip inductor$ L3 $120 \ nH \ chip inductor$ L4 $220 \ nH \ chip inductor$ L5 $12 \ nH \ chip inductor$ L6 $22 \ nH \ chip inductor$ L7 $150 \ nH \ chip inductor$	R2, R3, R4, R5, C2, L8	0Ω chip resistor			
R9, R10 200 Ω chip resistor R11 27 Ω chip resistor R16 10 Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 μ F chip capacitor C8, C10 1000 pF chip capacitor C11, C12, C13, Shown in silkscreen, but not C15 8.2 pF chip capacitor C17 22 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor	R6, R7	470 Ω chip resistor			
R11 27 Ω chip resistor R16 10 Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 µF chip capacitor C8, C10 1000 pF chip capacitor C11, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C17 22 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor	R8	3.3 Ω chip resistor			
R16 10 Ω chip resistor C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 µF chip capacitor C8, C10 1000 pF chip capacitor C11, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C17 22 pF chip capacitor C17 22 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L7 10 nH chip inductor	R9, R10	200Ω chip resistor			
C1, C3, C4, C5, C6 100 pF chip capacitor C7, C9, C16 0.018 µF chip capacitor C8, C10 1000 pF chip capacitor C1, C12, C13, Shown in silkscreen, but not C18, C21, F1 used in actual circuit. C15 8.2 pF chip capacitor C17 22 pF chip capacitor C13 120 nH chip inductor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L7 150 nH chip inductor	R11	27 Ω chip resistor			
C7, C9, C16 $0.018 \ \mu F$ chip capacitorC8, C10 $1000 \ pF$ chip capacitorC11, C12, C13,Shown in silkscreen, but notC18, C21, F1used in actual circuit.C14 $3.9 \ pF$ chip capacitorC15 $8.2 \ pF$ chip capacitorC17 $22 \ pF$ chip capacitorL218 nH chip inductorL3 $120 \ nH \ chip inductor$ L4 $220 \ nH \ chip inductor$ L5 $12 \ nH \ chip inductor$ L6 $22 \ nH \ chip inductor$ L7 $150 \ nH \ chip inductor$ L1010 \ nH \ chip inductor	R16	10 Ω chip resistor			
C8, C101000 pF chip capacitorC11, C12, C13, C18, C21, F1Shown in silkscreen, but not used in actual circuit.C143.9 pF chip capacitorC158.2 pF chip capacitorC1722 pF chip capacitorL218 nH chip inductorL3120 nH chip inductorL4220 nH chip inductorL512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	C1, C3, C4, C5, C6	100 pF chip capacitor			
C11, C12, C13, C18, C21, F1Shown in silkscreen, but not used in actual circuit.C143.9 pF chip capacitorC158.2 pF chip capacitorC1722 pF chip capacitorL218 nH chip inductorL3120 nH chip inductorL4220 nH chip inductorL512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	C7, C9, C16	0.018 µF chip capacitor			
C18, C21, F1used in actual circuit.C143.9 pF chip capacitorC158.2 pF chip capacitorC1722 pF chip capacitorL218 nH chip inductorL3120 nH chip inductorL4220 nH chip inductorL512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	C8, C10	1000 pF chip capacitor			
C14 3.9 pF chip capacitor C15 8.2 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor, size 0805 L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	C11, C12, C13,	Shown in silkscreen, but not			
C15 8.2 pF chip capacitor C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	C18, C21, F1	used in actual circuit.			
C17 22 pF chip capacitor L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	C14	3.9 pF chip capacitor			
L2 18 nH chip inductor L3 120 nH chip inductor L4 220 nH chip inductor, size 0805 L5 12 nH chip inductor L6 22 nH chip inductor L7 150 nH chip inductor L10 10 nH chip inductor	C15	8.2 pF chip capacitor			
L3120 nH chip inductorL4220 nH chip inductor, size 0805L512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	C17	22 pF chip capacitor			
L4220 nH chip inductor, size 0805L512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	L2	18 nH chip inductor			
L512 nH chip inductorL622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	L3	120 nH chip inductor			
L622 nH chip inductorL7150 nH chip inductorL1010 nH chip inductor	L4	220 nH chip inductor, size 0805			
L7150 nH chip inductorL1010 nH chip inductor	L5	12 nH chip inductor			
L10 10 nH chip inductor	L6	22 nH chip inductor			
	L7	150 nH chip inductor			
U1 CV110-1A WJ Converter	L10	10 nH chip inductor			
	U1	CV110-1A WJ Converter			

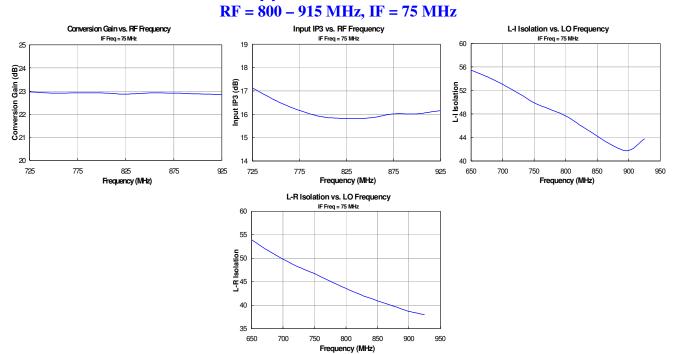
All components are of size 0603 unless otherwise specified.

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CV110-1APCB75 Application Circuit Performance Plots

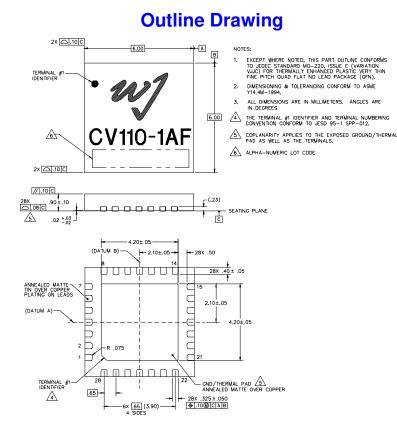




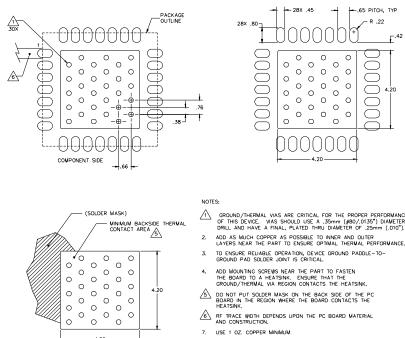


Mechanical Information

This package is lead-free/RoHS-compliant. The plating material on the pins is annealed matte tin over copper. It is compatible with both lead-free (maximum 260 °C reflow temperature) and leaded (maximum 245 °C reflow temperature) soldering processes.



Mounting Configuration / Land Pattern



ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES 8

Product Marking

The component will be lasermarked with a "CV110-1AF" product label with an alphanumeric lot code on the top surface of the package.

Tape and reel specifications for this part will be located on the website in the "Application Notes" section.

ESD / MSL Information

Caution! ESD sensitive device.

ESD Rating:	Class 1B
Value:	Passes \geq 500V to <1000V
Test:	Human Body Model (HBM)
Standard:	JEDEC Standard JESD22-A114

ESD Rating:	Class III
Value:	Passes \geq 500V to <1000V
Test:	Charged Device Model (CDM)
Standard:	JEDEC Standard JESD22-C101

MSL Rating: Level 2 at +260 °C convection reflow JEDEC Standard J-STD-020 Standard:

Functional Pin Layout

Pin	FUNCTION	Pin	FUNCTION
1	RF Amp Output	15	LO Amp Input
2	GND	16	GND
3	N/C	17	LO Amp Bias
4	GND	18	GND
5	IF Feedthru Port	19	N/C or GND
6	GND	20	GND
7	7 Mixer RF/		IF Amp
/	IF Port	21	Output/Bias
8	GND	22	GND
9	N/C or GND	23	IF Amp Input
10	GND	24	GND
11	Mixer LO Input	25	IF Feedthru Port
12	GND	26	GND
13	LO Amp Output	27	RF Amp Input
14	GND	28	GND

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BACK SIDE